



ESPRESSIF ESP32-WROOM-32UE WiFi BLE Module User Manual

[Home](#) » [ESPRESSIF](#) » ESPRESSIF ESP32-WROOM-32UE WiFi BLE Module User Manual 



ESPRESSIF

ESP32-WROOM-32UE
User Manual

About This Document

This document provides the specifications for the ESP32-WROOM-32UE modules with PIFA antenna.

Contents

- [1 Overview](#)
- [2 Pin Definitions](#)
- [3 Functional Description](#)
- [4 Peripherals and Sensors](#)
- [5 Electrical Characteristics](#)
- [6 FCC statement](#)
- [7 Documents / Resources](#)
- [8 Related Posts](#)

Overview

ESP32-WROOM-32UE is a powerful, generic WiFi-BT-BLE MCU module that targets a wide variety of applications, ranging from low-power sensor networks to the most demanding tasks, such as voice encoding, music streaming, and MP3 decoding.

It is with all GPIOs on the pin-out except the ones already used for connecting flash. The Module's working voltage can range from 3.0 V to 3.6 V. Frequency range is 24

12 MHz to 24 62 MHz. External 40 MHz as the clock source for the system. There is also a 4 MB SPI flash for storing user programs and data. The ordering information of ESP32-WROOM-32UE is listed as follows:

Table 1: ESP32-WROOM-32UE Ordering Information

Module	Chip embedded	Flash	PSRAM	Module dimensions (mm)
ESP32-WROOM-32UE	ESP32-D0WD-V3	4 MB 1	/	(18.00 ± 0.10) X (25.50 ± 0.10) X (3.10 ± 0.10) mm (including metallic shield)
Notes: 1. ESP32-WROOM-32UE (IPEX) with 8 MB flash or 16 MB flash is available for a custom order. 2. For detailed ordering information, please see Espressif Product Ordering Information.				

At the core of the module is the ESP32-D0WD-V3 chip*. The chip embedded is designed to be scalable and adaptive. There are two CPU cores that can be individually controlled, and the CPU clock frequency is adjustable from 80 MHz to 240 MHz. The user may also power off the CPU and make use of the low-power co-processor to constantly monitor the peripherals for changes or crossing of thresholds. ESP32 integrates a rich set of peripherals, ranging from capacitive touch sensors, Hall sensors, SD card interface, Ethernet, high-speed SPI, UART, I²S, and I²C.

Note:

* For details on the part numbers of the ESP32 family of chips, please refer to the document ESP32 User Manual.

The integration of Bluetooth, Bluetooth LE, and Wi-Fi ensures that a wide range of applications can be targeted and that the module is all-around: using Wi-Fi allows a large physical range and direct connection to the Internet through a Wi-Fi router while using Bluetooth allows the user to conveniently connect to the phone or broadcast low-energy beacons for its detection. The sleep current of the ESP32 chip is less than 5 A, making it suitable for battery-powered and wearable electronics applications. The module supports a data rate of up to 150 Mbps. As such the module does offer industry-leading specifications and the best performance for electronic integration, range, power consumption, and connectivity.

The operating system chosen for ESP32 is freeRTOS with LwIP; TLS 1.2 with hardware acceleration is built in as well. Secure (encrypted) over-the-air (OTA) upgrade is also supported, so that users can upgrade their products even after their release, at minimum cost and effort. Table 2 provides the specifications of ESP32-WROOM-32UE.

Table 2: ESP32-WROOM-32UE Specifications

Categories	Items	Specifications
------------	-------	----------------

Test	Reliability	HTOUHTSUuHASTfTCT/ESD
Wi-Fi	Protocols	802.11 b/g/n 20/n40
		A-MPDU and A-MSDU aggregation and 0.4 s guard interval support
	Frequency range	2.412 GHz – 2.462GHz
Bluetooth	Protocols	Bluetooth v4.2 BR/EDR and BLE specification
	Radio	NZIF receiver with -97 dBm sensitivity
		Class-1, class-2 and class-3 transmitter
		AFH
	AUDIO	CVSD and SBC
Hardware	Module interfaces	SD card, UART, SPI, SDIO, I2C, LED PWM, Motor PWN 12S, IR, pulse counter, GPIO, capacitive touch sensor, ADC, DAC
	On-chip sensor	Hall sensor
	Integrated crystal	40 MHz crystal
	Integrated SPI flash	4 MB
	Integrated PSRAM	–
	Operating voltage/Power supply	3.0 V – 3.6 V
	Minimum current delivered by the power supply	500 mA
	Recommended operating temperature range 40 °C – 85 °C	
	Package size	(18.00±0.10) mm x (31.40±0.10) mm x (3.30±0.10) mm
	Moisture sensitivity level (MSL)	Level 3

Pin Definitions

2.1 Pin Layout

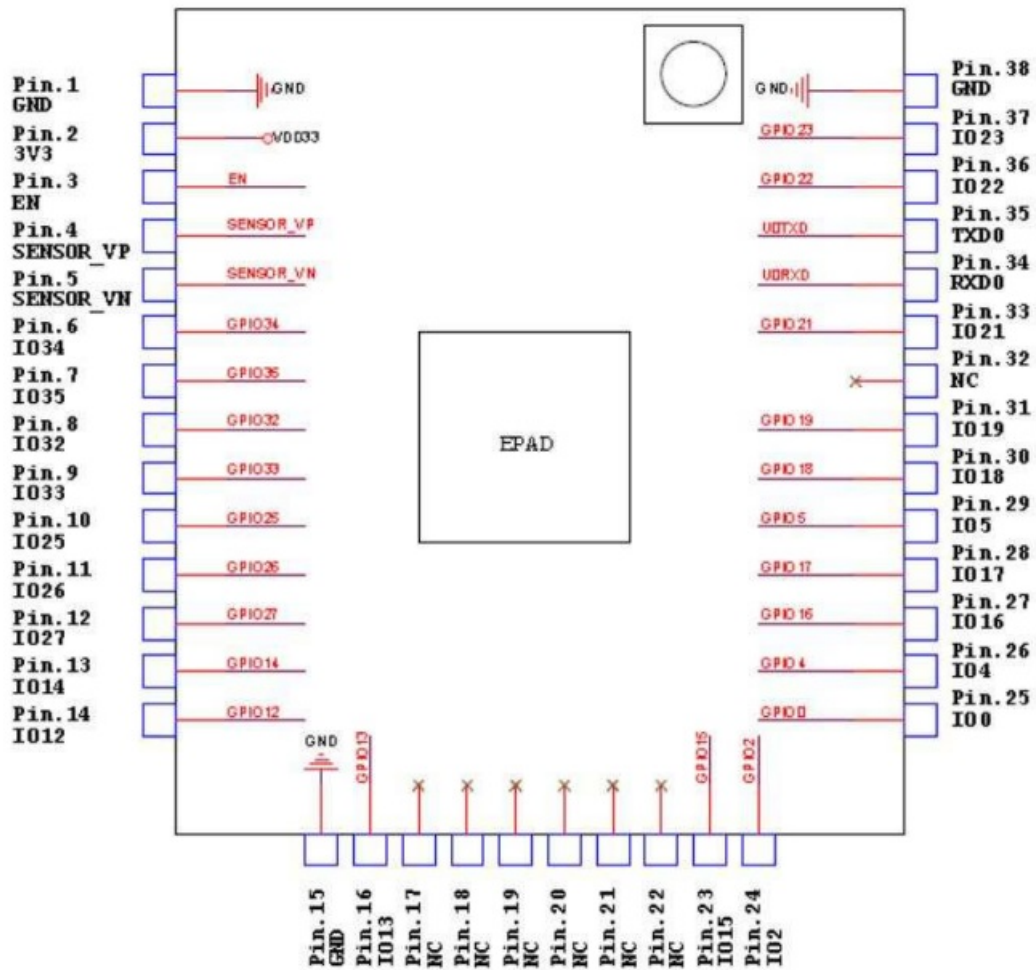


Figure 1: Pin Layout of ESP32-WROOM-32UE (Top View)

2.2 Pin Description

ESP32-WROOM-32UE has 38 pins. See pin definitions in Table 3.

Table 3: Pin Definitions

Name	No.	Type	Function
GND	1	P	Ground
3V3	2	P	Power supply
EN	3	I	Module-enable signal. Active high.
SENSOR VP	4	I	GPI036, ADC1_CHO, RTC_GPIO0
SENSOR VN	5	I	GPI039, ADC1 CH3, RTC GP103
1034	6	I	GPI034, ADC1_CH6, RTC_GPIO4
1035	7	I	GPI035, ADC1_CH7, RTC_GPIO5
1032	8	I/O	GPI032, XTAL 32K P (32.768 kHz crystal oscillator input), ADC1_CH4 TO UCH9, RTC GP109

1033	9	1/O	GPIO33, XTAL_32K_N (32.768 kHz crystal oscillator output), ADC1 CH5, TOUCH8, RTC GP108
1025	10	I/O	GPIO25, DAC_1, ADC2_CH8, RTC_GPIO6, EMAC_RXDO
1026	11	1/O	GPIO26, DAC_2, ADC2_CH9, RTC_GPIO7, EMAC_RXD1
1027	12	1/O	GPIO27, ADC2_CH7, TOUCH7, RTC_GPIO17, EMAC_RX_DV
1014	13	I/O	GPIO14, ADC2 CH6, TOUCH6, RTC GPIO16, MTMS, HSPICLK, HS2_CLK, SD_CLK, EMAC_TXD2
1012	14	I/O	GPIO12, ADC2_CH5, TOUCH5, RTC GPIO15, MTDI, HSPIQ, HS2_DATA2, SD_DATA2, EMAC_TXD3
GND	15	P	Ground
1013	16	I/O	GPIO13, ADC2 CH4, TOUCH4, RTC GPIO14, MTCK, HSPID, HS2_DATA3, SD_DATA3, EMAC_RX_ER
NC	17	—	—
NC	18	—	—
NC	19	—	—
NC	20	—	—
NC	21	—	—
NC	22	—	—
1015	23	I/O	GPIO15, ADC2 CH3, TOUCH3, MTDO, HSPICSO, RTC GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3
102	24	1/O	GPIO2, ADC2_CH2, TOUCH2, RTC GPIO12, HSPIWP, HS2_DATA0, SD DATA()
100	25	I/O	GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1, IMAC TX CLK — —
104	26	I/O	GPIO4, ADC2_CHO, TOUCH, RTC_GPIO10, HSPIHD, HS2_DATA1, SD DATA1, EMAC_TX_ER
1016	27	1/O	GPIO16, ADC2_CH8, TOUCH
1017	28	1/O	GPIO17, ADC2_CH9, TOUCH11
105	29	1/O	GPIO5, VSPICSO, HS1_DATA6, EMAC_RX_CLK
1018	30	1/O	GPIO18, VSPICLK, HS1_DATA7

Name	No.	Type	Function
1019	31	I/O	GPIO19, VSPIQ, UOCTS, EMAC_TXDO
NC	32	—	—
1021	33	I/O	GPIO21, VSPIHD, EMAC_TX_EN
RXDO	34	I/O	GPIO3, UORXD, CLK_OUT2
TXDO	35	I/O	GPIO1, UOTXD, CLK_OUT3, EMAC_RXD2
1022	36	I/O	GPIO22, VSPIWP, UORTS, EMAC_TXD1
1023	37	I/O	GPIO23, VSPID, HS1_STROBE
GND	38	P	Ground

Notice:

* GPIO6 to GPIO11 are connected to the SPI flash integrated on the module and are not connected out.

2.3 Strapping Pins

ESP32 has five strapping pins, which can be seen in Chapter 6 Schematics:

- MTDI
- GPIO0
- GPIO2
- MTDO
- GPIO5

The software can read the values of these five bits from the register "GPIO_STRAPPING". During the chip's system reset release (power-on-reset, RTC watchdog reset, and brownout reset), the latches of the strapping pins sample the voltage level as strapping bits of "0" or "1", and hold these bits until the chip is powered down or shut down. The strapping bits configure the device's boot mode, the operating voltage of VDD_SDIO, and other initial system settings.

Each strapping pin is connected to its internal pull-up/pull-down during the chip reset. Consequently, if a strapping pin is unconnected or the connected external circuit is high-impedance, the internal weak pull-up/pull-down will determine the default input level of the strapping pins.

To change the strapping bit values, users can apply the external pull-down/pull-up resistances, or use the host MCU's GPIOs to control the voltage level of these pins when powering on ESP32. After reset release, the strapping pins work as normal-function pins. Refer to Table 4 for a detailed boot-mode configuration by strapping pins.

Table 4: Strapping Pins

Voltage of Internal LDO (VDD_SDIO)			
Pin	Default	3.3 V	1.8 V
MTDI	Pull-down	0	1

Bootling Mode				
Pin	Default SPI Boot		Download Boot	
GPIO0	Pull-up 1		0	
GPIO2	Pull-down Don't-care		0	
Enabling/Disabling Debugging Log Print over UOTXD During Bootling				
Pin	Default UOTXD Active		UOTXD Silent	
MTDO	Pull-up 1		0	
Timing of SDIO Slave				
Pin	Falling-edge Sampling Default Falling-edge Output	Falling-edge Sampling Rising-edge Output	Rising-edge Sampling Falling-edge Output	Rising-edge Sampling Rising-edge Output
MTDO	Pull-up 0	0	1	1
GPIO5	Pull-up 0	1	0	1

Note:

- Firmware can configure register bits to change the settings of "Voltage of Internal LDO (VDD_SDIO)" and "Timing of SDIO Slave" after bootling.
- Internal pull-up resistor (R9) for MTDI is not populated in the module, as the flash and SRAM in ESP32-WROOM-32UE only support a power voltage of 3.3 V (output by VDD_SDIO)

Functional Description

This chapter describes the modules and functions integrated with ESP32-WROOM-32UE.

3.1 CPU and Internal Memory

ESP32-D0WD-V3 contains two low-power Xtensa® 32-bit LX6 microprocessors. The internal memory includes:

- 448 KB of ROM for bootling and core functions.
- 520 KB of on-chip SRAM for data and instructions.
- 8 KB of SRAM in RTC, which is called RTC FAST Memory and can be used for data storage; it is accessed by the main CPU during RTC Boot from the Deep-sleep mode.
- 8 KB of SRAM in RTC, which is called RTC SLOW Memory and can be accessed by the co-processor during the Deep-sleep mode.
- 1 Kbit of eFuse: 256 bits are used for the system (MAC address and chip configuration) and the remaining 768 bits are reserved for customer applications, including flash encryption and chip-ID.

3.2 External Flash and SRAM

ESP32 supports multiple external QSPI flash and SRAM chips. More details can be found in Chapter SPI in the ESP32 Technical Reference Manual. ESP32 also supports hardware encryption/decryption based on AES to protect developers' programs and data in flash.

ESP32 can access the external QSPI flash and SRAM through high-speed caches.

- The external flash can be mapped into CPU instruction memory space and read-only memory space simultaneously.
 - When the external flash is mapped into CPU instruction memory space, up to 11 MB + 248 KB can be mapped at a time. Note that if more than 3 MB + 248 KB are mapped, cache performance will be reduced due to speculative reads by the CPU.
 - When an external flash is mapped into read-only data memory space, up to 4 MB can be mapped at a time. 8-bit, 16-bit, and 32-bit reads are supported.
 - External SRAM can be mapped into CPU data memory space. Up to 4 MB can be mapped at a time. 8-bit, 16-bit, and 32-bit read and writes are supported.
- ESP32-WROOM-32UE integrates a 4 MB SPI flash more memory space.

3.3 Crystal Oscillators

The module uses a 40-MHz crystal oscillator.

3.4 RTC and Low-Power Management

With the use of advanced power-management technologies, ESP32 can switch between different power modes. For details on ESP32's power consumption in different power modes, please refer to section "RTC and Low-Power Management" in ESP32 User Manual.

Peripherals and Sensors

Please refer to Section Peripherals and Sensors in the ESP32 User Manual.

Note:

External connections can be made to any GPIO except for GPIOs in the range 6-11, 16, or 17. GPIOs 6-11 are connected to the module's integrated SPI flash. For details, please see Section 6 Schematics.

Electrical Characteristics

5.1 Absolute Maximum Ratings

Stresses beyond the absolute maximum ratings listed in the table below may cause permanent damage to the device. These are stress ratings only, and do not refer to the functional operation of the device that should follow the recommended operating conditions.

Table 5: Absolute Maximum Ratings

1. The module worked properly after a 24-hour test in ambient temperature at 25 °C, and the IOs in three domains (VDD3P3_RTC, VDD3P3_CPU, VDD_SDIO) output high logic level to the ground. Please note that pins occupied by flash and/or PSRAM in the VDD_SDIO power domain were excluded from the test.
2. Please see Appendix IO_MUX of ESP32 User Manual for IO's power domain.

5.2 Recommended Operating Conditions

Table 6: Recommended Operating Conditions

Symbol	Parameter	Min	Typical	Max	Unit
VDD33	Power supply voltage	3.0	3.	4.	V
I_V	Current delivered by the external power supply	0.5	—	—	A
T	Operating temperature	—40	—	85	°C

5.3 DC Characteristics (3.3 V, 25 °C)

Table 7: DC Characteristics (3.3 V, 25 °C)

Symbol	Parameter		Min	Typ	Max	Unit
C_{IN}	Pin capacitance			2	—	pF
V_{IH}	High-level input voltage		$0.75 \times V_{DD1}$	—	$V_{DD1} + 0.3$	V
V_{IL}	Low-level input voltage		—0.3	—	$0.25 \times V_{DD1}$	V
i_{IH}	High-level input current		—	—	50	nA
i_{IL}	Low-level input current			—	50	nA
V_{OH}	High-level output voltage		$0.8 \times V_{DD1}$			V
VOA	Low-level output voltage			—		V
I_{OH1}	High-level source current ($V_{DD1} = 3.3$ V, $V_{OH} \geq 2.6$ V, output drive strength set to the maximum)	VDD3P3 CPU power domain 1 ; 2	—	40	—	mA
		VDD3P3 RTC power domain 1 ; 2	—	40	—	mA
		VDD SDIO power domain 1 ; 3	—	20	—	mA

Symbol	Parameter	Min	Typ	Max	Unit
I_{OL10}	Low-level sink current ($V_{DD1} = 3.3$ V, $V_{OL} = 0.495$ V, output drive strength set to the maximum)	—	28		mA
R_{PU}	Resistance of internal pull-up resistor	—	45	—	kil
R_{PD}	Resistance of internal pull-down resistor	—	45	—	kil
V_{IL_nRST}	Low-level input voltage of CHIP_PU to power off the chip	—	—	0.6	V

Notes:

1. Please see Appendix IO_MUX of ESP32 User Manual for IO's power domain. VDD is the I/O voltage for a particular power domain of pins.
2. For VDD3P3_CPU and VDD3P3_RTC power domain, per-pin current sourced in the same domain is gradually reduced from around 40 mA to around 29 mA, $V_{OH} \geq 2.64$ V, as the number of current-source pins increases.
3. Pins occupied by flash and/or PSRAM in the VDD_SDIO power domain were excluded from the test.

5.4 Wi-Fi Radio

Table 8: Wi-Fi Radio Characteristics

Parameter	Condition	Min	Typical	Max	Unit
Operating frequency range notes		2412	—	2462	MHz
Output impedance note2			*		C2
TX power note3		802.11b:24.16dBm;802.11g:23.52dBm 802.11n20:23.0dBm;802.11n40:21.18dBm			
Sensitivity	11b, 1 Mbps	—	—98		dBm
	11b, 11 Mbps	—	—89		dBm
	11g, 6 Mbps		—92	—	dBm
	11g, 54 Mbps		—74	—	dBm
	11n, HT20, MCS0		—91	—	dBm
	11n, HT20, MCS7		—71		dBm
	11n, HT40, MCS0		—89		dBm
	11n, HT40, MCS7		—69		dBm
Adjacent channel rejection	11g, 6 Mbps		31	—	dB
	11g, 54 Mbps		14		dB
	11n, HT20, MCS0		31		dB
	11n, HT20, MCS7	—	13		dB

1. Device should operate in the frequency range allocated by regional regulatory authorities. Target operating frequency range is configurable by software.
2. For the modules that use IPEX antennas, the output impedance is 50 Ω . For other modules without IPEX antennas, users do not need to be concerned about the output impedance.
3. Target TX power is configurable based on device or certification requirements.

5.5 Bluetooth/BLE Radio

5.5.1 Receiver

Table 9: Receiver Characteristics – Bluetooth/BLE

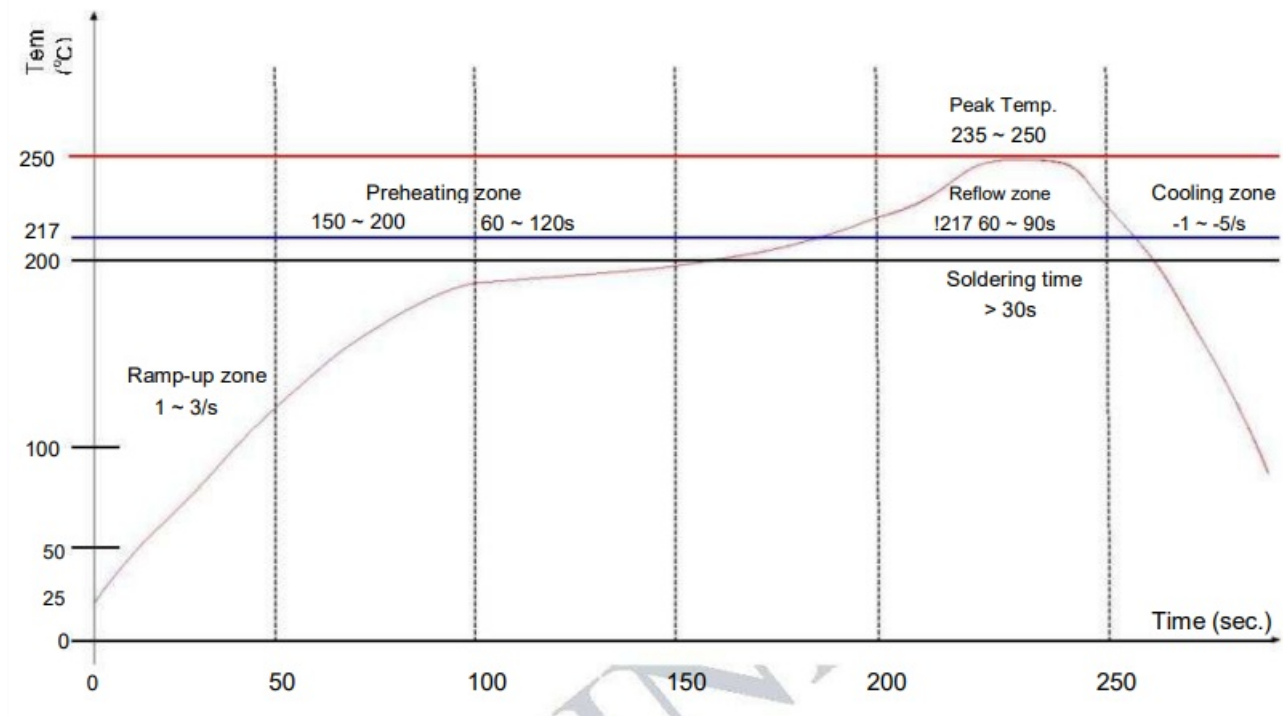
Parameter	Conditions	Min	Typ	Max	Unit
Sensitivity @30.8% PER			-97	–	dBm
Maximum received signal @30.8% PER	–	0	–	–	dBm
Co-channel C/I	–	–	+10	–	dB
Adjacent channel selectivity C/I	$F = FO + 1 \text{ MHz}$	–	-5	–	dB
	$F = FO - 1 \text{ MHz}$	–	-5	–	dB
	$F = FO + 2 \text{ MHz}$	–	-25	–	dB
	$F = FO - 2 \text{ MHz}$	–	-35	–	dB
	$F = FO + 3 \text{ MHz}$	–	-25	–	dB
	$F = FO - 3 \text{ MHz}$	–	-45	–	dB
Out-of-band blocking performance	30 MHz – 2000 MHz	-10	–	–	dBm
	2000 MHz – 2400 MHz dBm	-27	–	–	
	2500 MHz – 3000 MHz	-27	–	–	dBm
	3000 MHz – 12.5 GHz	-10	–	–	dBm
itiudulatitm 1	–	-36	–	–	dBm

5.5.2 Transmitter

Table 10: Transmitter Characteristics – Bluetooth/BLE

Parameter	Conditions	Min	Typ	Max	Unit
Gain control step			3		dBm
RF power	–		BT3.0:7.73dBm BLE:4.92dBm	dBm	
Adjacent channel transmits power	$F = FO \pm 2 \text{ MHz}$	–	–52	–	dBm
	$F = FO \pm 3 \text{ MHz}$	–	–58	–	dBm
	$F = FO \pm > 3 \text{ MHz}$		–60	–	dBm
A flaw	–		–	265	kHz
a fzmax		247	–		kHz
An f2avq/A f1avg	–		–0.92	–	–
1CFT	–		–10	–	kHz
Drift rate			0.7	–	kHz/50 s
Drift	–		2	–	kHz

5.6 Reflow Profile



Ramp-up zone — Temp.: <150 Time: 60 ~ 90s Ramp-up rate: 1 ~ 3/s

Preheating zone — Temp.: 150 ~ 200 Time: 60 ~ 120s Ramp-up rate: 0.3 ~ 0.8/s

Reflow zone — Temp.: >217 7LPH60 ~ 90s; Peak Temp.: 235 ~ 250 (<245 recommended) Time: 30 ~ 70s

Cooling zone — Peak Temp. ~ 180 Ramp-down rate: -1 ~ -5/s

Solder — Sn&Ag&Cu Lead-free solder (SAC305)

Revision History

Date	Version	Release notes
2020.02	V0.1	Preliminary release for certification CE.

OEM Guidance

1. Applicable FCC rules

This module is granted Single Modular Approval. It complies with the requirements of FCC part 15C, section 15.247 rules.

2. The specific operational use conditions

This module can be used in RF devices. The input voltage to the module is nominally 3.0V-3.6 V DC. The operational ambient temperature of the module is – 40 to 85 degrees C.

3. Limited module procedures

N/A

4. Trace antenna design

N/A

5. RF exposure considerations

The equipment complies with FCC radiation exposure limits set forth for an uncontrolled environment. This equipment should be installed and operated with a minimum distance of 20cm between the radiator and your body. If the equipment is built into a host for portable usage, the additional RF exposure evaluation may be

required as specified by 2.1093.

6. Antenna

Antenna type: PIFA antenna with IPEX connector; Peak gain: 4dBi

7. Label and compliance information

An exterior label on OEM's end product can use wording such as the following:

"Contains FCC ID: 2AC7Z-ESPWROOM32UE" and

"Contains IC: 21098-ESPWROOMUE"

8. Information on test modes and additional testing requirements

a)The modular transmitter has been fully tested by the module grantee on the required number of channels, modulation types, and modes, it should not be necessary for the host installer to re-test all the available transmitter modes or settings. It is recommended that the host product manufacturer, install the modular transmitter, and perform some investigative measurements to confirm that the resulting composite system does not exceed the spurious emissions limits or band edge limits (e.g., where a different antenna may be causing additional emissions).

b)The testing should check for emissions that may occur due to the intermixing of emissions with the other transmitters, digital circuitry, or due to physical properties of the host product (enclosure). This investigation is especially important when integrating multiple modular transmitters where the certification is based on testing each of them in a stand-alone configuration. It is important to note that host product manufacturers should not assume that because the modular transmitter is certified that they do not have any responsibility for final product compliance.

c)If the investigation indicates a compliance concern the host product manufacturer is obligated to mitigate the issue. Host products using a modular transmitter are subject to all the applicable individual technical rules as well as to the general conditions of operation in Sections 15.5, 15.15, and 15.29 to not cause interference. The operator of the host product will be obligated to stop operating the device until the interference has been corrected.

9. Additional testing, Part 15 Subpart B disclaimer The final host/module combination needs to be evaluated against the FCC Part 15B criteria for unintentional radiators in order to be properly authorized for operation as a Part 15 digital device. The host integrator installing this module into their product must ensure that the final composite product complies with the FCC requirements by a technical assessment or evaluation of the FCC rules, including the transmitter operation, and should refer to the guidance in KDB 996369. For host products with a certified modular transmitter, the frequency range of investigation of the composite system is specified by rule in Sections 15.33(a)(1) through (a)(3), or the range applicable to the digital device, as shown in Section 15.33(b)(1), whichever is the higher frequency range of investigation When testing the host product, all the transmitters must be operating. The transmitters can be enabled by using publicly- available drivers and turned on, so the transmitters are active. In certain conditions, it might be appropriate to use a technology-specific call box (test set) where accessory 50 devices or drivers are not available. When testing for emissions from the unintentional radiator, the transmitter shall be placed in the receive mode or idle mode, if possible. If receive mode only is not possible then, the radio shall be passive (preferred) and/or active scanning. In these cases, this would need to enable activity on the communication BUS (i.e., PCIe, SDIO, USB) to ensure the unintentional radiator circuitry is enabled. Testing laboratories may need to add attenuation or filters depending on the signal strength of any active beacons (if applicable)

from the enabled radio(s). See ANSI C63.4, ANSI C63.10, and ANSI C63.26 for further general testing details.

The product under test is set into a line association with a partnering device, as per the normal intended use of the product. To ease testing, the product under test is set to transmit at a high duty cycle, such as by sending a

file or streaming some media content.

FCC statement

This device complies with Part 15 of the FCC Rules. Operation is subject to the following two conditions:

- (1) this device may not cause harmful interference, and (2) this device must accept any interference
(2) received, including interference that may cause undesired operation.

FCC Caution:

Any changes or modifications not expressly approved by the party responsible for compliance could void the user's authority to operate the equipment.


"This equipment has been tested and found to comply with the limits for a Class B digital device, pursuant to part 15 of the FCC Rules. These limits are designed to protect reasonably against harmful interference in a residential installation. This equipment generates, uses, and can radiate radio frequency energy and, if not installed and used in accordance with the instructions, may cause harmful interference to radio communications. However, there is no guarantee that interference will not occur in a particular installation. If this equipment does cause harmful interference to radio or television reception, which can be determined by turning the equipment off and on, the user is encouraged to try to correct the interference by one or more of the following measures:

- Reorient or relocate the receiving antenna.
- Increase the separation between the equipment and receiver.
- Connect the equipment into an outlet on a circuit different from that to which the receiver is connected.
- Consult the dealer or an experienced radio/TV technician for help."

IC statement:

This device complies with Industry Canada licence-exempt RSS standard(s). Operation is subject to the following two conditions: (1) this device may not cause interference, and (2) this device must accept any interference, including interference that may cause undesired operation of the device.

Documents / Resources

	<p>ESPRESSIF ESP32-WROOM-32UE WiFi BLE Module [pdf] User Manual ESPWROOM32UE, 2AC7Z-ESPWROOM32UE, 2AC7ZESPWROOM32UE, ESP32-WROOM-32UE WiFi BLE Module, ESP32-WROOM-32UE, WiFi BLE Module</p>
---	--